# onsemi

# Integrated Load Switch FDC6331L

#### Description

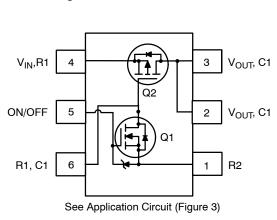
This device is particularly suited for compact power management in portable electronic equipment where 2.5 V to 8 V input and 2.8 A output current capability are needed. This load switch integrates a small N-Channel power MOSFET (Q1) that drives a large P-Channel power MOSFET (Q2) in one tiny SUPERSOT  $^{\text{M}}$ -6 package.

#### Features

- -2.8 A, -8 V
  - $R_{DS(on)} = 55 \text{ m}\Omega @ V_{GS} = -4.5 \text{ V}$
  - $R_{DS(on)} = 70 \text{ m}\Omega @ V_{GS} = -2.5 \text{ V}$
  - $R_{DS(on)} = 100 \text{ m}\Omega @ V_{GS} = -1.8 \text{ V}$
- Control MOSFET (Q1) Includes Zener Protection for ESD Ruggedness (>6 kV Human Body Model)
- High Performance Trench Technology for Extremely Low RDS(on)
- This is a Pb-Free and Halide Free Device

#### Applications

- Load Switch
- Power Management





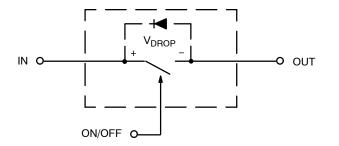


Figure 2. Equivalent Circuit



TSOT-23-6 CASE 419BL

#### MARKING DIAGRAM



= Designates Space

- = Binary Calendar Year Coding Scheme
- = Pin One Dot

&E

&Y

&. 331

&G

= Specific Device Code

= Date Code

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
FDC6331L	TSOT-23-6 (Pb-Free)	3000 / Tape & Reel

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

# FDC6331L

#### **ABSOLUTE MAXIMUM RATINGS** $T_A = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Unit	
V <sub>IN</sub>	Maximum Input Voltage	±8	V	
V <sub>ON/OFF</sub>	High Level On/Off Voltage Range	–0.5 to 8	V	
I <sub>Load</sub>	Load Current – Continuous (Note 1)	2.8	А	
	Load Current - Pulsed	9		
PD	Maximum Power Dissipation (Note 1) 0.7		W	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	–55 to 150	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### **THERMAL CHARACTERISTICS** $T_A = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Unit
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (Note 1)	180	°C/W
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction-to-Case (Note 1)	60	°C/W

#### **ELECTRICAL CHARACTERISTICS** $T_A = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
FF CHARAC	TERISTICS					
BV <sub>IN</sub>	V <sub>IN</sub> Breakdown Voltage	$V_{ON/OFF}$ = 0 V, $I_D$ = -250 $\mu$ A	8	-	-	V
I <sub>Load</sub>	Zero Gate Voltage Drain Current	V <sub>IN</sub> = 6.4 V, V <sub>ON/OFF</sub> = 0 V	-	-	-1	μA
I <sub>FL</sub>	Leakage Current, Forward	$V_{ON/OFF} = 0 V, V_{IN} = 8 V$	-	-	-100	nA
I <sub>RL</sub>	Leakage Current, Reverse	$V_{ON/OFF} = 0$ V, $V_{IN} = -8$ V	-	-	100	nA
N CHARACT	ERISTICS (Note 2)					
V <sub>ON/OFF(th)</sub>	Gate Threshold Voltage	$V_{IN} = V_{ON/OFF}$ , $I_D = -250 \ \mu A$	0.4	0.9	1.5	V
R <sub>DS(on)</sub>	Static Drain-Source On-Resistance (Q2)	$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -2.8 \text{ A}$	-	34	55	mΩ
		$V_{GS} = -2.5 \text{ V}, \text{ I}_{D} = -2.5 \text{ A}$	-	45	70	
		$V_{GS} = -1.8$ V, $I_D = -2.0$ A	-	64	100	
R <sub>DS(on)</sub>	Static Drain–Source On–Resistance (Q1)	$V_{GS}$ = 4.5 V, I <sub>D</sub> = 0.4 A	-	3.1	4	Ω
		$V_{GS} = 2.7 \text{ V}, I_D = 0.2 \text{ A}$	-	3.8	5	

#### DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS

I <sub>S</sub>	Maximum Continuous Drain-Source Diode Forward Current		-	-	-0.6	Α
V <sub>SD</sub>	Drain-Source Diode Forward Voltage	V <sub>ON/OFF</sub> = 0 V, I <sub>S</sub> = -0.6 A (Note 2)	-	ĺ	-1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### NOTES:

 R<sub>0JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>0JC</sub> is guaranteed by design while R<sub>0JA</sub> is determined by the user's board design.

2. Pulse Test: Pulse Width < 300 µs, Duty Cycle < 2.0%.

### FDC6331L

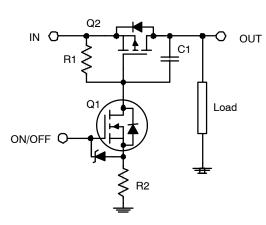
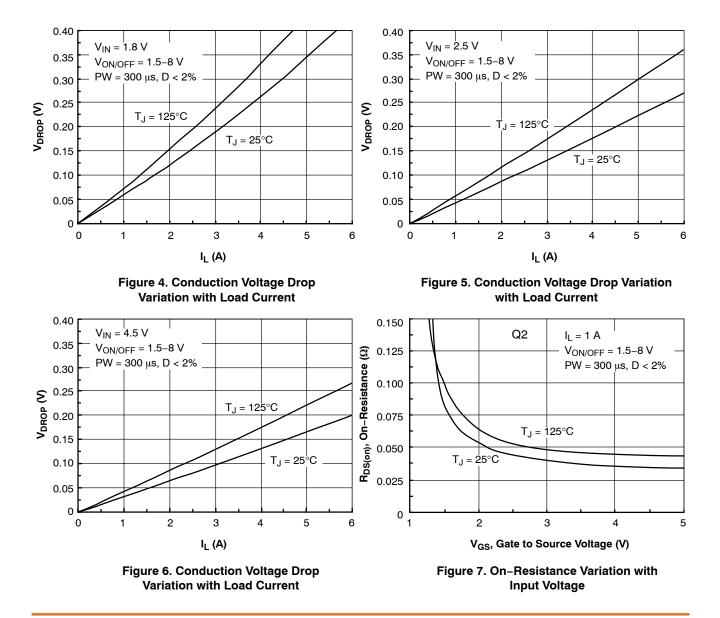


Figure 3. FDC6331L Load Switch Application Circuit

External Component Recommendation:

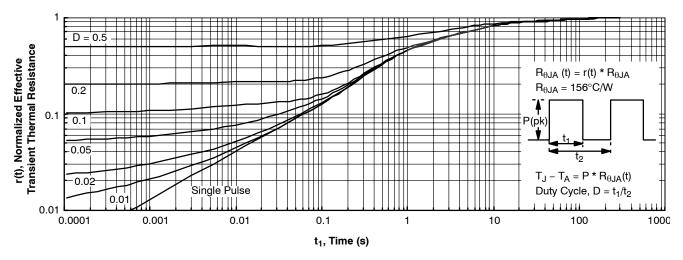
For additional in-rush current control, R2 and C1 can be added. For more information, see application note AN1030.

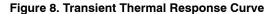


#### **TYPICAL CHARACTERISTICS**

## FDC6331L

#### TYPICAL CHARACTERISTICS (continued)

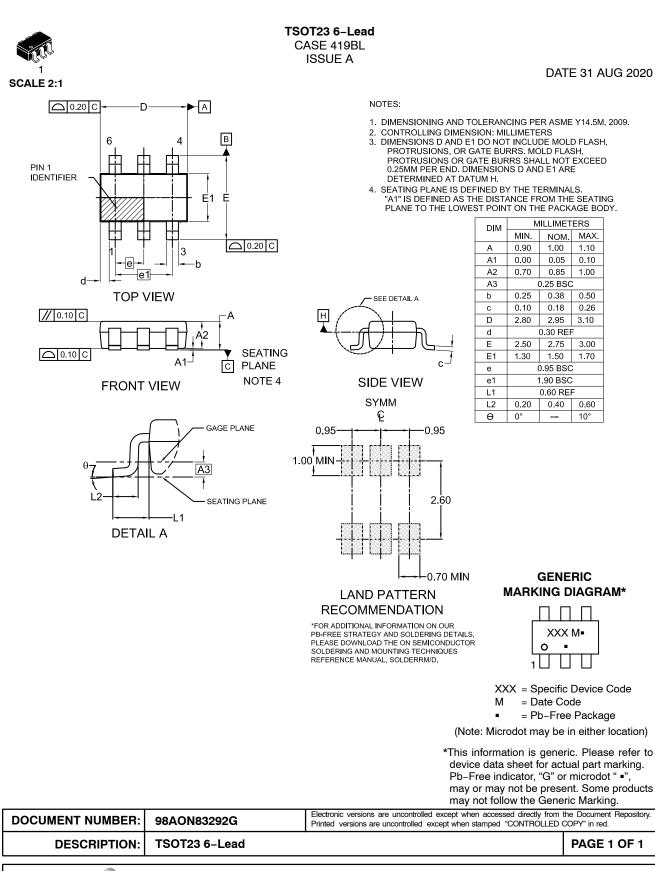




NOTE: Thermal characterization performed on the conditions described in Note 2. Transient thermal response will change depends on the circuit board design.

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